NSN 5961-01-190-7775

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Inclosure Material:
Metal
Overall Length:
Between 0.240 inches and 0.260 inches
Terminal Length:
0.500 inches
Overall Diameter:
Between 0.350 inches and 0.370 inches
Internal Configuration:
Junction contact
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
То-39
Mounting Method:
Terminal
Terminal Circle Diameter:
Between 0.192 inches and 0.210 inches
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
-8.0 breakdown voltage, collector-to-emitter, base open and -80.0 breakdown voltage, collector-to-base, emitter open
Current Rating Per Characteristic:
-1.00 amperes source cutoff current
Power Rating Per Characteristic:
800.0 milliwatts small-signal input power, common-collector absolute
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius junction
Special Features:
Junction pattern arrangement: pnp
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
-
Demilitarization:
Yes - demil/mli
Fiig:
A110a0